

Amendments to the Claims:

The listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (Currently Amended) An array for producing a Micro Electro Mechanical System (MEMS) device comprising:

 ~~pluralities of various types of~~ circuit elements including a plurality of
circuit elements of [[for]] each type, and

 switches for connecting each of said circuit elements, wherein

 at least one of said switches are connected on each side of said circuit
elements, and

 some of said circuit elements are interconnected by determining open or
close an on/off state of all of said switches so as to make a circuit, ~~and~~

 ~~some of said elements are produced on a substrate by utilizing Micro~~
~~Electro-Mechanical System technology.~~
2. (Currently Amended) An array for producing a MEMS device as set forth in claim 1, wherein the switches connecting the circuit elements are semiconductor switches.
3. (Withdrawn) A MEMS array as set forth in claim 1, wherein the switches connecting the elements are mechanical switches.

4. (Currently Amended) An array for producing a MEMS device as set forth in claim 1, provided with an interconnect layer, said substrate being formed with said switches, said interconnect layer provided with a plurality of circuit elements connected through said switches.

5. (Currently Amended) An array for producing a MEMS device as set forth in claim 4, wherein said substrate is provided with drive parts for driving said switches.

6. (Currently Amended) An array for producing a MEMS device as set forth in claim 5, wherein said substrate is further provided with semiconductor circuits for signal processing.

7. (Currently Amended) An array for producing a MEMS device as set forth in claim 6, wherein said semiconductor circuits have three-dimensional structures.

8-11. (Canceled)

12. (Withdrawn) A MEMS array as set forth in claim 1, provided with a substrate and interconnect layer, said interconnect layer provided with a plurality of elements, switches for connecting said elements being provided on the interconnect layer.

13. (Withdrawn) A MEMS array as set forth in claim 12, wherein said substrate is provided with drive parts for driving said switches.

14. (Withdrawn) A MEMS array as set forth in claim 13, wherein said substrate is provided with semiconductor circuits for signal processing.

15. (Withdrawn) A MEMS array as set forth in claim 14, wherein said semiconductor circuits have three-dimensional structures.

16. (Currently Amended) An array for producing a MEMS device as set forth in claim 1, wherein the same package packages semiconductor circuits built therein.

17. (Withdrawn) A method of production of a MEMS array providing an interconnect layer on a substrate, said method of production of a MEMS array characterized by having: a step of forming a plurality of switches in said substrate and a step of forming pluralities of various types of elements for each type connected through said plurality of switches in said interconnect layer.

18. (Withdrawn) A method of production of a MEMS array providing an interconnect layer on a substrate, said method of production of a MEMS array characterized by having: a step of forming pluralities of various types of elements for each type in said interconnect layer and a step of providing a plurality of switches for connecting said elements on said interconnect layer.

19. (Withdrawn) A method of production of a MEMS array providing an interconnect layer on a substrate, said method of production of a MEMS array characterized by having: a step of forming switch drive parts on said substrate, a step of forming pluralities of various types of elements for each type in said interconnect layer, and a step of providing a plurality of switches for connecting said elements on said interconnect layer.

20. (Withdrawn) A method of production of a MEMS device having a plurality of elements of the same arrangement as a MEMS array provided with a plurality of elements and switches for connecting said elements, said method of production of a MEMS device characterized by having: a step of determining connection states of switches of said MEMS array and a step of forming an interconnect layer connecting elements in accordance with the connection states of said switches.

21. (Withdrawn) A method of production of a MEMS device having a plurality of elements of the same arrangement as a MEMS array provided with a plurality of elements and switches for connecting said elements, said method of production of a MEMS device characterized by having: a step of determining connection states of switches of said MEMS array, a step of forming an interconnect layer connecting elements in accordance with the connection states of said switches on the substrate of said MEMS device, and a step of forming a

plurality of elements of the same arrangement as the MEMS array on said interconnect layer.

22. (Withdrawn) A method of production of a MEMS device having a plurality of elements of the same arrangement as a MEMS array provided with a plurality of elements and switches for connecting said elements, said method of production of a MEMS device characterized by having: a step of determining connection states of switches of said MEMS array, a step of providing switches in the substrate of the MEMS device, a step of providing an additional interconnect layer for short-circuiting, opening, or connecting said switches in accordance with the connection states of said switches on the substrate of the MEMS device, and a step of providing an interconnect layer arranging a plurality of elements of the same arrangement as said MEMS array on said additional interconnect layer.

23. (Withdrawn) A method of production of a MEMS device having a plurality of elements of the same arrangement as a MEMS array provided with a plurality of elements and switches for connecting said elements, said method of production of a MEMS device characterized by having: a step of determining connection states of switches of said MEMS array, a step of forming an interconnect layer providing a plurality of elements of the same arrangement as said MEMS array, and a step of selectively forming switches and interconnects on said interconnect layer based on the connection states of said switches.